



44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089

NTE980 Integrated Circuit CMOS, Micropower Phase-Locked Loop (PLL)

Description:

The NTE980 CMOS Micropower Phase-Locked Loop (PLL) consists of a low-power, linear voltage-controlled oscillator (VCO) and two different phase comparators having a common signal-input amplifier and a common comparator input in a 16-Lead type package. A 5.2V zener diode is provided for supply regulation if necessary.

Features:

- Very Low Power Consumption: $70\mu\text{W}$ (Typ) @ VCO $f_0 = 10\text{kHz}$, $V_{DD} = 5\text{V}$
- Operating Frequency Range up to 1.4MHz (Typ) @ $V_{DD} = 10\text{V}$, $R_I = 5\text{k}\Omega$
- Low Frequency Drift: $0.04\%/\text{^oC}$ (Typ) @ $V_{DD} = 10\text{V}$
- Choice of Two Phase Comparators:
 - Exclusive-OR Network (I)
 - Edge-Controlled Memory Network w/Phase-Pulse Output for Lock Indication (II)
- High VCO Linearity: $< 1\%$ (Typ) @ $V_{DD} = 10\text{V}$
- VCO Inhibit Control for ON-OFF Keying and Ultra-Low Standby Power Consumption
- Source-Follower Output of VCO Control Input (Demod. Output)
- Zener Diode to Assist Supply Regulation
- Standardized, Symmetrical Output Characteristics
- 100% Tested for Quiescent Current at 20V
- 5V, 10V, and 15V Parametric Ratings

Applications:

- FM Demodulator and Modulator
- Frequency Synthesis and Multiplication
- Frequency Discriminator
- Signal Conditioning
- FSK – Modems
- Data Synchronization
- Voltage-to-Frequency Conversion
- Tone Decoding

Absolute Maximum Ratings:

DC Supply Voltage Range (Voltages referenced to V_{SS} terminal), V_{DD}	-0.5 to +20V
Input Voltage Range, All Inputs	-0.5 to $V_{DD}+0.5\text{V}$
DC Input Current, Any One Input	$\pm 10\text{mA}$
Power Dissipation ($T_A = -40^\circ$ to $+60^\circ\text{C}$), P_D	500mW
$T_A = +60^\circ$ to $+85^\circ\text{C}$	Derate Linearly at $12\text{mW}/^\circ\text{C}$ to 200mW
Device Dissipation Per Output Transistor ($T_A = -40^\circ$ to $+85^\circ\text{C}$)	100mW
Operating Temperature Range, T_A	-40° to $+85^\circ\text{C}$
Storage Temperature Range, T_{stg}	-65° to $+150^\circ\text{C}$
Lead Temperature (During Soldering, $1/16'' \pm 1/32''$ from case, 10sec Max), T_L	+265°C

Recommended Operating Conditions: ($T_A = -40^\circ$ to $+85^\circ\text{C}$)

Parameter	Min	Typ	Max	Unit
Supply Voltage Range VCO Section: As Fixed Oscillator	3	—	18	V
Phase-Lock-Loop Operation	5	—	18	V
Supply Voltage Range Phase Comparator Section: Comparators	3	—	18	V
VCO Operation	5	—	18	V

Static Electrical Characteristics: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions			Min	Typ	Max	Unit	
		V_O	V_{IN}	V_{DD}					
VCO Section									
Output Low (Sink) Current	$I_{OL\text{Min}}$	400mV	0V, 5V	5V	0.51	1.0	—	mA	
		500mV	0V, 10V	10V	1.3	2.6	—	mA	
		1.5V	0V, 15V	15V	3.4	6.8	—	mA	
Output High (Source) Current	$I_{OH\text{Min}}$	4.6V	0V, 5V	5V	-0.51	-1.0	—	mA	
		2.5V	0V, 5V	5V	-1.6	-3.2	—	mA	
		9.5V	0V, 10V	10V	-1.3	-2.6	—	mA	
		13.5V	0V, 15V	15V	-3.4	-6.8	—	mA	
Output Voltage: Low-Level	$V_{OL\text{Max}}$	Pin4 driving CMOS e.g. Pin3	0V, 5V	5V	—	0	0.05	V	
			0V, 10V	10V	—	0	0.05	V	
			0V, 15V	15V	—	0	0.05	V	
Output Voltage: High-Level	$V_{OH\text{Max}}$		0V, 5V	5V	4.95	5.0	—	V	
			0V, 10V	10V	9.95	10.0	—	V	
			0V, 15V	15V	14.95	15.0	—	V	
Input Current	$I_{IN\text{Max}}$	—	0V, 18V	18V	—	$\pm 10^{-5}$	± 0.1	μA	
Phase Comparator Section									
Total Device Current Pin14 = Open, Pin5 = V_{DD}	$I_{DD\text{Max}}$	—	0V, 5V	5V	—	0.1	0.2	mA	
		—	0V, 10V	10V	—	0.5	1.0	mA	
		—	0V, 15V	15V	—	0.75	1.5	mA	
		—	0V, 20V	20V	—	2.0	4.0	mA	
		—	0V, 5V	5V	—	10.0	20.0	μA	
		—	0V, 10V	10V	—	20.0	40.0	μA	
		—	0V, 15V	15V	—	40.0	80.0	μA	
		—	0V, 20V	20V	—	80.0	160.0	μA	
Output Low (Sink) Current	$I_{OL\text{Min}}$	400mV	0V, 5V	5V	0.51	1.0	—	mA	
		500mV	0V, 10V	10V	1.3	2.6	—	mA	
		1.5V	0V, 15V	15V	3.4	6.8	—	mA	
Output High (Source) Current	$I_{OH\text{Min}}$	4.6V	0V, 5V	5V	-0.51	-1.0	—	mA	
		2.5V	0V, 5V	5V	-1.6	-3.2	—	mA	
		9.5V	0V, 10V	10V	-1.3	-2.6	—	mA	
		13.5V	0V, 15V	15V	-3.4	-6.8	—	mA	

Static Electrical Characteristics (Cont'd): ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions			Min	Typ	Max	Unit
		V_O	V_{IN}	V_{DD}				
Phase Comparator Section (Cont'd)								
DC Coupled Signal Input and Comparator Input Voltage Sensitivity Low Level	$V_{IL\text{Max}}$	0.5V, 4.5V	—	5V	—	—	1.5	V
		1V, 9V	—	10V	—	—	3.0	V
		1.5V, 13.5V	—	15V	—	—	4.0	V
High Level	$V_{IH\text{Max}}$	0.5V, 4.5V	—	5V	3.5	—	—	V
		1V, 9V	—	10V	7.0	—	—	V
		1.5V, 13.5V	—	15V	11.0	—	—	V
Input Current (Except Pin14)	$I_{IN\text{Max}}$	—	0V, 18V	18V	—	$\pm 10^{-5}$	± 0.1	μA
3-State Leakage Current	$I_{OUT\text{Max}}$	0V, 18V	0V, 18V	18V	—	$\pm 10^{-5}$	± 0.1	μA

Electrical Characteristics: ($T_A = +25^\circ\text{C}$)

Parameter	Symbol	Test Conditions			V_{DD}	Min	Typ	Max	Unit
VCO Section									
Operating Power Dissipation	P_D	$f_0 = 10\text{kHz}$, $R_2 = \infty$	$R_1 = 1\text{M}\Omega$, $V_{CO\text{IN}} = \frac{V_{DD}}{2}$	5V	—	70	140	μW	
				10V	—	800	1600	μW	
				15V	—	3000	6000	μW	
Maximum Operating Frequency	f_{max}	$C_1 = 50\text{pF}$, $R_2 = \infty$, $V_{CO\text{IN}} = V_{DD}$	$R_1 = 10\text{k}\Omega$	5V	0.3	0.6	—	MHz	
				10V	0.6	1.2	—	MHz	
				15V	0.8	1.6	—	MHz	
			$R_1 = 5\text{k}\Omega$	5V	0.5	0.8	—	MHz	
				10V	1.0	1.4	—	MHz	
				15V	1.4	2.4	—	MHz	
Linearity		$V_{CO\text{IN}} = 2.5\text{V} \pm 0.3\text{V}$	$R_1 = 10\text{k}\Omega$	5V	—	1.7	—	%	
			$R_1 = 100\text{k}\Omega$	10V	—	0.5	—	%	
			$R_1 = 400\text{k}\Omega$	10V	—	4.0	—	%	
			$R_1 = 100\text{k}\Omega$	15V	—	0.5	—	%	
			$R_1 = 1\text{M}\Omega$	15V	—	7.0	—	%	
Temperature-Frequency Stability: No Frequency Offset	$f_{MIN} = 0$		5V	—	± 0.12	—	$\text{%/}^\circ\text{C}$		
			10V	—	± 0.04	—	$\text{%/}^\circ\text{C}$		
			15V	—	± 0.015	—	$\text{%/}^\circ\text{C}$		
Frequency Offset	$f_{MIN} \neq 0$		5V	—	± 0.09	—	$\text{%/}^\circ\text{C}$		
			10V	—	± 0.07	—	$\text{%/}^\circ\text{C}$		
			15V	—	± 0.03	—	$\text{%/}^\circ\text{C}$		
Output Duty Cycle			5, 10, 15V	—	50	—	%		
Output Transition Times	t_{THL}, t_{TLH}		5V	—	100	200	ns		
			10V	—	50	100	ns		
			15V	—	40	80	ns		

Electrical Characteristics (Cont'd): ($T_A = +25^\circ\text{C}$)

Parameter	Symbol	Test Conditions		V_{DD}	Min	Typ	Max	Unit
VCO Section (Cont'd)								
Source-Follower Output (Demodulated Output): Offset Voltage	$V_{CO_{IN}} - V_{DEM}$	$R_S > 10\text{k}\Omega$		5V	—	1.8	2.5	V
				10V	—	1.8	2.5	V
				15V	—	1.8	2.5	V
Linearity		$V_{CO_{IN}} = 2.5\text{V} \pm 0.3\text{V}$	$R_S = 100\text{k}\Omega$	5V	—	0.3	—	%
		$V_{CO_{IN}} = 5.0\text{V} \pm 2.5\text{V}$	$R_S = 300\text{k}\Omega$	10V	—	0.7	—	%
		$V_{CO_{IN}} = 7.5\text{V} \pm 5.0\text{V}$	$R_S = 500\text{k}\Omega$	15V	—	0.9	—	%
Zener Diode Voltage	V_Z	$I_Z = 50\mu\text{A}$		—	4.45	5.50	6.15	V
Zener Dynamic Resistance	R_Z	$I_Z = 1\text{mA}$		—	—	40	—	Ω
Phase Comparator Section								
Pin14 (Signal In) Input Resistance	R_{14}			5V	1.0	2.0	—	$\text{M}\Omega$
				10V	0.2	0.4	—	$\text{M}\Omega$
				15V	0.1	0.2	—	$\text{M}\Omega$
AC Coupled Signal Input Voltage Sensitivity (Peak-to-Peak)		$f_{IN} = 100\text{kHz}$, Sine Wave, Note 1		5V	—	180	360	mV
				10V	—	330	660	mV
				15V	—	900	1800	mV
Propagation Delay Time (Pin14 to Pin13) High to Low Level	t_{PHL}			5V	—	225	450	ns
				10V	—	100	200	ns
				15V	—	65	130	ns
Low to High Level	t_{PLH}			5V	—	350	700	ns
				10V	—	150	300	ns
				15V	—	100	200	ns
3-State Propagation Delay Time (Pin14 to Pin13) High Level to Low Impedance	t_{PHZ}			5V	—	225	450	ns
				10V	—	100	200	ns
				15V	—	95	190	ns
Low Level to High Impedance	t_{PLZ}			5V	—	285	570	ns
				10V	—	130	260	ns
				15V	—	95	190	ns
Input Rise or Fall Times Comparator Input (Pin3)	t_r, t_f			5V	—	—	50.0	μs
				10V	—	—	1.0	μs
				15V	—	—	0.3	μs
Signal Input (Pin14)				5V	—	—	500.0	μs
				10V	—	—	20.0	μs
				15V	—	—	2.5	μs
Output Transition Times	t_{THL}, t_{TLH}			5V	—	100	200	ns
				10V	—	50	100	ns
				15V	—	40	80	ns

Note 1. For sine wave, the frequency must be greater than 10kHz for Phase Comparator II.

Pin Connection Diagram

